

# isc N-Channel MOSFET Transistor

## 2SK3716

### **FEATURES**

- Drain Current : I<sub>D</sub>= 60A@ T<sub>C</sub>=25℃
- Drain Source Voltage : V<sub>DSS</sub>= 40V(Min)
- Static Drain-Source On-Resistance
- : R<sub>DS(on)</sub> = 6.5m Ω (Max) @ V<sub>GS</sub>= 10V
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRIPTION

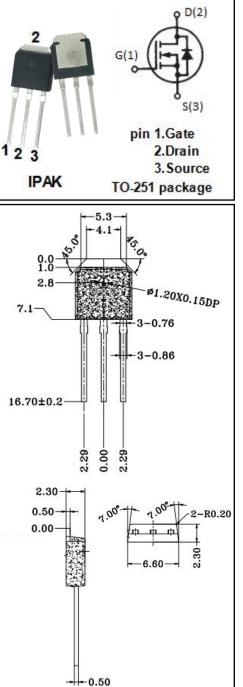
· motor drive, DC-DC converter, power switch and solenoid drive.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)							
PARAMETER	VALUE	UNIT					
Drain-Source Voltage	40	V					
Gate-Source Voltage-Continuous	±20	V					
Drain Current-Continuous	60	А					
Drain Current-Single Pluse	240	A					
Total Dissipation @T <sub>C</sub> =25℃	84	W					
Max. Operating Junction Temperature	-55~150	°C					
Storage Temperature	-55~150	°C					
	PARAMETER   Drain-Source Voltage   Gate-Source Voltage-Continuous   Drain Current-Continuous   Drain Current-Single Pluse   Total Dissipation @Tc=25°C   Max. Operating Junction Temperature	PARAMETERVALUEDrain-Source Voltage40Gate-Source Voltage-Continuous±20Drain Current-Continuous60Drain Current-Single Pluse240Total Dissipation @Tc=25°C84Max. Operating Junction Temperature-55~150					

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### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	1.49	°C/W





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### **ELECTRICAL CHARACTERISTICS**

#### T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 1.0mA	40		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> = 1.0mA	1.5	2.5	V
R <sub>DS</sub> (on)	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 30A		6.5	mΩ
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0		±10	uA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 40V; V <sub>GS</sub> = 0		10	uA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 60A; V <sub>GS</sub> = 0		1.5	V

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